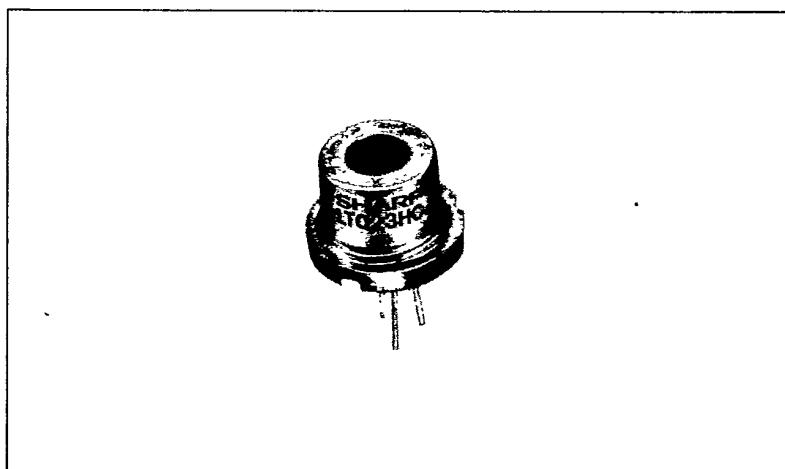


LT023HC**Features**

- Wide temperature range ($-30^{\circ}\text{C} \sim +85^{\circ}\text{C}$)
- Low noise
S/N: 80 dB (according to measurement method Fig. 29-2)
- Wavelength: 780nm
- Single transverse mode
- Multi longitudinal mode

Applications

- Video disc players
- Fiber optic communications
- Light source for analog processing
- Measurement instruments
- Analysis instruments

**Absolute Maximum Ratings**

(Tc=25°C)

Parameter	Symbol	Ratings	Units
Optical power output	Po	5	mW
Reverse voltage	V _R	2	V
PIN	V _R	30	
Operating temperature *1	T _{opr}	-30 ~ +85	°C
Storage temperature *1	T _{stg}	-40 ~ +100	°C
Soldering temperature *2	T _{sol}	260 (less than 5 seconds)	°C

*1 Case temperature *2 At point 1.6 mm from lead base

Electro-optical Characteristics *1

(Tc=25°C)

Parameter	Symbol	Condition	Ratings			Units		
			MIN	TYP	MAX			
Threshold current	I _{th}	—	—	50	90	mA		
Operating current	I _{op1}	Po=3mW	—	65	110	mA		
Operating voltage	V _{op}	Po=3mW	—	1.75	2.2	V		
Wavelength *2	λ _p	Po=3mW	770	780	795	nm		
Monitor current	I _m	Po=3mW V _R =15V	0.3	0.9	1.6	mA		
Radiation characteristics	Angle *3	Parallel to junction	θ //	Po=3mW	9	11	16	deg
		Perpendicular to junction	θ ⊥	Po=3mW	20	37	48	deg
Emission point accuracy	Ripple	—	—	Po=3mW	—	—	±20	%
		—	—	Po=3mW	—	—	±2	deg
	Angle	Δφ //	—	Po=3mW	—	—	±3	deg
		Δφ ⊥	—	Po=3mW	—	—	±80	μm
Differential efficiency	η	—	2mW I _f (3mW) - I _f (1mW)	0.1	0.25	0.6	mW/mA	
Coherence	γ	Po=3mW	—	—	—	0.47		

*1 Initial value *3 Angle at 50% peak intensity (full width at half-maximum)

*2 Single transverse mode

Electrical Characteristics of Photodiode

(Tc=25°C)

Parameter	Symbol	Condition	Ratings			Units
			MIN	TYP	MAX	
Sensitivity	S	V _R =15V	—	0.3	—	mA/mW
Dark current	I _D	V _R =15V	—	—	250	nA
Terminal capacitance	C _t	V _R =15V	—	8	20	pF